



P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	RDS(ON) max	Package	I _D Ta = +25°C
-25V	27mΩ @ V _{GS} = -4.5V	U-DFN2020-6	-6.7A
-25V	40mΩ @ V _{GS} = -1.8V	(Type E)	-5.4A

Description

This new generation MOSFET has been designed to minimize the onstate resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Pin1

Applications

- Load Switching
- Battery Management Application
- Power Management Functions

Features

- Low R_{DS(ON)} Ensures on State Losses are Minimized
- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- ESD Protected Gate
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

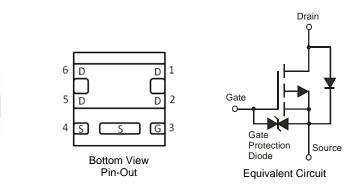
https://www.diodes.com/products/automotive/automotiveproducts/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208⁽³⁾
- Weight: 0.001 grams (Approximate)



Ordering Information (Note 4)

ESD PROTECTED

Part Number	Case	Packaging
DMP2039UFDE-7	U-DFN2020-6 (Type E)	3,000/Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

U-DFN2020-6 (Type E)

Bottom View



Marking Information

Site 1



P9 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key

Year	2011		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	Y		Н		J	К	L	М	N	0	Р	R
					-					-	-	
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2



P9 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date	Code	Kev
Daio	oouc	1100

Year	2011		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	1		0	1	2	3	4	5	6	7	8	9
									1			
Week		1-	26			27-	-52			5	3	
Code		A	-Z			a	-Z			2	2	
Internal Code	Sur	n	Mon		Tue	w	ed	Thu		Fri		Sat
Code	T		U		V		V	X		Y		Z



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit V		
Drain-Source Voltage		VDSS	-25			
Gate-Source Voltage			V _{GSS}	±8	V	
	Steady State	T _A = +25°C T _A = +70°C	ID	-6.7 -5.3	А	
Continuous Drain Current (Note 5) $V_{GS} = -4.5V$	t<5s	T _A = +25°C T _A = +70°C	ID	-8.3 -6.6	A	
	Steady State	T _A = +25°C T _A = +70°C	ID	-5.4 -4.3	А	
Continuous Drain Current (Note 5) $V_{GS} = -1.8V$	t<5s	T _A = +25°C T _A = +70°C	ID	-6.6 -5.2	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%		Ідм	-60	А		
Continuous Source-Drain Diode Current			Is	-2.0	А	

Thermal Characteristics

Characteristic		Symbol	Value	Unit	
Total Power Dissipation (Note 5)	T _A = +25°C	D-	0.8	W	
Total Power Dissipation (Note 5)	$T_A = +70^{\circ}C$	PD	1.2	vv	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	D	160	°C/W	
Thermal Resistance, Sunction to Ambient (Note 5)	t<5s	RθJA	104	C/W	
Tatal Dawar Disaination (Nata C)	$T_A = +25^{\circ}C$	D-	2.0	W	
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	PD	2.9		
Thermal Registeres, Junction to Ambient (Note 6)	Steady State	D	63	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t<5s	RθJA	42	°C/vv	
Thermal Resistance, Junction to Case (Note 6)	Steady State	Rejc	10.8	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)			- 76			
Drain-Source Breakdown Voltage	BVDSS	-25	_		V	Vgs = 0V, Id = -250µA
Zero Gate Voltage Drain Current	IDSS		_	-1	μA	$V_{DS} = -25V, V_{GS} = 0V$
Gate-Source Leakage	lgss		_	±10	μA	V _{GS} = ±8.0V, V _{DS} = 0V
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	-0.4	_	-1.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
			20	27		VGS = -4.5V, ID = -6.4A
Static Drain-Source On-Resistance	Descer	_	24	34	mΩ	$V_{GS} = -2.5V, I_D = -4.8A$
Static Drain-Source On-Resistance	RDS(ON)	_	28	40	11122	V _{GS} = -1.8V, I _D = -2.5A
		_	33	70		Vgs = -1.5V, ID = -1.5A
Forward Transfer Admittance	Y _{fs}	_	16	_	S	$V_{DS} = -5V, I_{D} = -4A$
Diode Forward Voltage	Vsd	_	-0.7	-1.0	V	$V_{GS} = 0V, I_{S} = -1A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		2530		pF	
Output Capacitance	Coss		203	_	pF	Vps = -15V, Vgs = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss		177	_	pF	
Gate Resistance	Rg		9.1	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1.0MHz$
Total Gate Charge (V _{GS} = -4.5V)	Qg		28.2	_	nC	
Total Gate Charge (V _{GS} = -8V	Qg		48.7	_	nC	
Gate-Source Charge	Qgs	_	3.2	_	nC	$V_{DS} = -15V, I_D = -4.0A$
Gate-Drain Charge	Qgd	_	5.0		nC	7
Turn-On Delay Time	tD(ON)	_	15.1		ns	
Turn-On Rise Time	tR		23.5		ns	$V_{DD} = -15V, V_{GS} = -4.5V, R_G = 1\Omega,$
Turn-Off Delay Time	tD(OFF)		137.6		ns	I _D = -4.0A
Turn-Off Fall Time	tF	_	80.5	_	ns	

Notes:

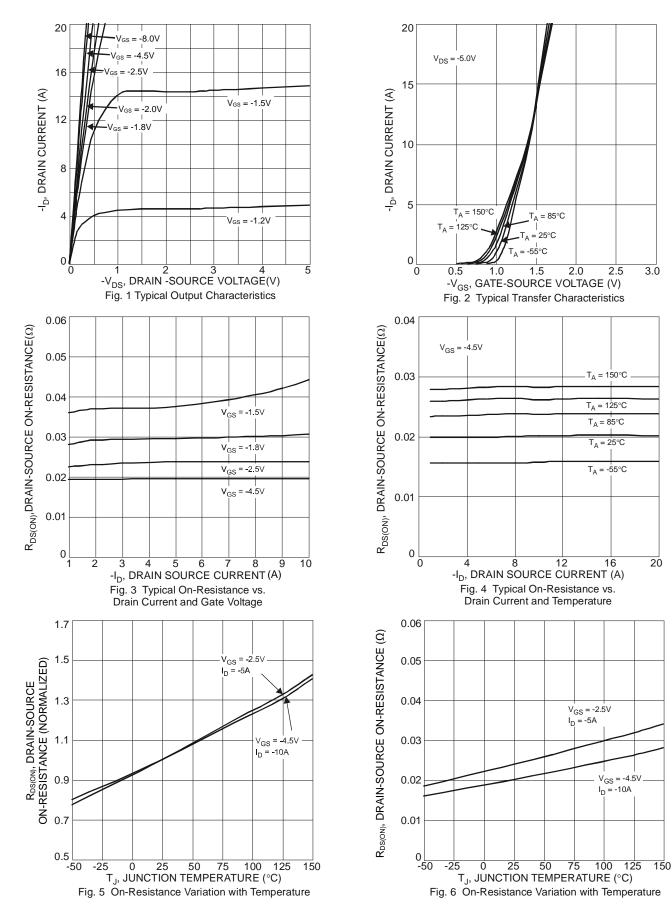
Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to production testing.

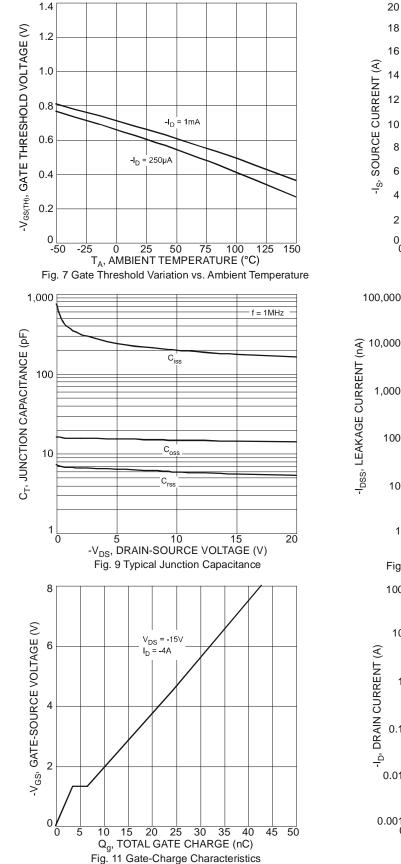
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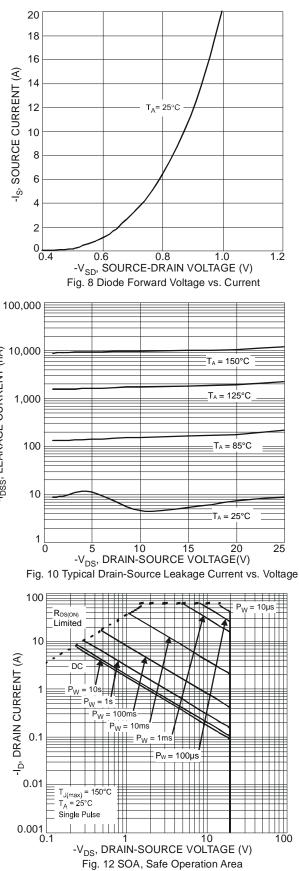




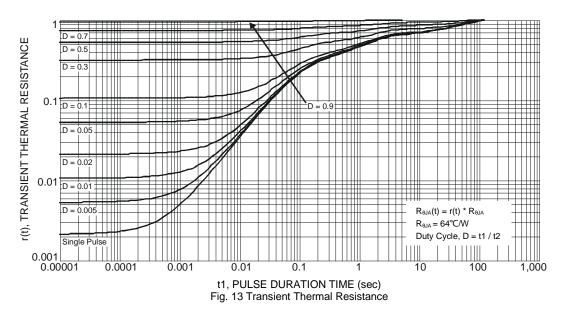


DMP2039UFDE





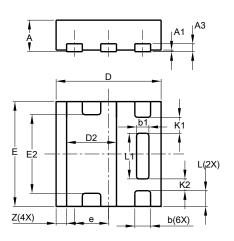






Package Outline Dimensions

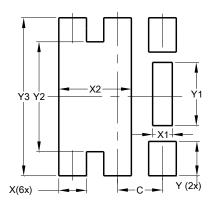
Please see http://www.diodes.com/package-outlines.html for the latest version.



	U-DFN2020-6						
		/pe E					
Dim	Min	Max	Тур				
Α	0.57	0.63	0.60				
A1	0	0.05	0.03				
A3	-	-	0.15				
b	0.25	0.35	0.30				
b1	0.185	0.285	0.235				
D	1.95	2.05	2.00				
D2	0.85	1.05	0.95				
E	1.95	2.05	2.00				
E2	1.40	1.60	1.50				
е	-	-	0.65				
L	0.25	0.35	0.30				
L1	0.82	0.92	0.87				
K1	_	-	0.305				
K2	_	_	0.225				
Z	_	-	0.20				
All	Dimen	isions i	in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



U-DFN2020-6 (Type E)

U-DFN2020-6 (Type E)

Dimensions	Value (in mm)
С	0.650
Х	0.400
X1	0.285
X2	1.050
Y	0.500
Y1	0.920
Y2	1.600
Y3	2.300



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